

Data sheet acquired from Harris Semiconductor SCHS181D

High-Speed CMOS Logic Hex Buffer/Line Driver, Three-State Non-Inverting and Inverting

November 1997 - Revised October 2003

#### Features

- · Buffered Inputs
- . High Current Bus Driver Outputs
- Two Independent Three-State Enable Controls
- Typical Propagation Delay t<sub>PLH</sub>, t<sub>PHL</sub> = 8ns at V<sub>CC</sub> = 5V, C<sub>L</sub> = 15pF, T<sub>Δ</sub> = 25°C
- Fanout (Over Temperature Range)
  - Standard Outputs...... 10 LSTTL Loads
  - Bus Driver Outputs ...... 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,
     V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

# Description

The 'HC367, 'HCT367, 'HC368, and CD74HCT368 silicon gate CMOS three-state buffers are general purpose high-speed non-inverting and inverting buffers. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The 'HC367 and 'HCT367 are non-inverting buffers, whereas the 'HC368 and CD74HCT368 are inverting buffers. These devices have two output enables, one enable (OE1) controls 4 gates and the other (OE2) controls the remaining 2 gates.

The 'HCT367 and CD74HCT368 logic families are speed, function and pin compatible with the standard LS logic family.

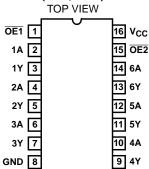
#### Ordering Information

DARTHUMBER	TEMP. RANGE	DACKAGE
PART NUMBER	(°C)	PACKAGE
CD54HC367F3A	-55 to 125	16 Ld CERDIP
CD54HC368F3A	-55 to 125	16 Ld CERDIP
CD54HCT367F3A	-55 to 125	16 Ld CERDIP
CD74HC367E	-55 to 125	16 Ld PDIP
CD74HC367M	-55 to 125	16 Ld SOIC
CD74HC367MT	-55 to 125	16 Ld SOIC
CD74HC367M96	-55 to 125	16 Ld SOIC
CD74HC368E	-55 to 125	16 Ld PDIP
CD74HC368M	-55 to 125	16 Ld SOIC
CD74HC368MT	-55 to 125	16 Ld SOIC
CD74HC368M96	-55 to 125	16 Ld SOIC
CD74HCT367E	-55 to 125	16 Ld PDIP
CD74HCT367M	-55 to 125	16 Ld SOIC
CD74HCT367MT	-55 to 125	16 Ld SOIC
CD74HCT367M96	-55 to 125	16 Ld SOIC
CD74HCT368E	-55 to 125	16 Ld PDIP
CD74HCT368M	-55 to 125	16 Ld SOIC
CD74HCT368MT	-55 to 125	16 Ld SOIC
CD74HCT368M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

## **Pinouts**

CD54HC367, CD54HCT367 (CERDIP) CD74HC367, CD74HCT367 (PDIP, SOIC) TOP VIEW

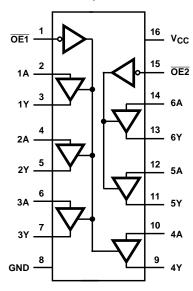


CD54HC368 (CERDIP) CD74HC368, CD74HCT368 (PDIP, SOIC) TOP VIEW

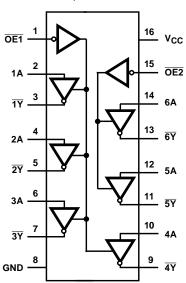
1	(PDIP, SOIC)	
	TOP VIEW	
OE1 1 1A 2 1Y 3 2A 4 2Y 5 3A 6 3Y 7	TOP VIEW	16 V <sub>CC</sub> 15 OE2 14 6A 13 6Y 12 5A 11 5Y 10 4A
GND 8		9 4Y

# Functional Diagrams

HC367, HCT367



#### HC368, CD74HCT368



#### **TRUTH TABLE**

INP	UTS	OUTPUTS (Y)				
ŌĒ	Α	HC/HCT367	HC/HCT368			
L	L	L	Н			
L	Н	Н	L			
Н	Х	(Z)	(Z)			

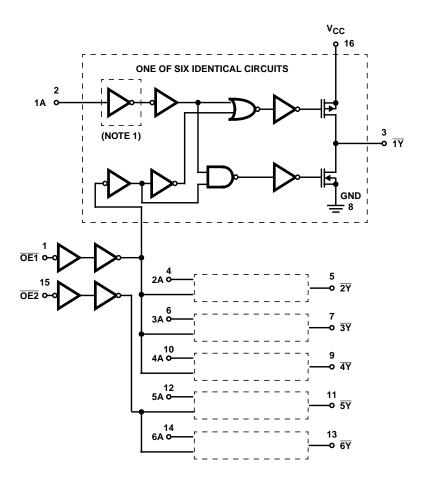
H = High Voltage Level

L = Low Voltage Level

X = Don't Care

Z = High Impedance (OFF) State

# Logic Diagram



#### NOTE:

1. Inverter not included in HC/HCT367

FIGURE 1. LOGIC DIAGRAM FOR THE HC/HCT367 AND HC/HCT368 (OUTPUTS FOR HC/HCT367 ARE COMPLEMENTS OF THOSE SHOWN, i.e., 1Y, 2Y, ETC.)

## **Absolute Maximum Ratings**

#### 

#### **Thermal Information**

Thermal Resistance (Typical, Note 2)	$\theta_{JA}$ (°C/W)
E (PDIP) Package	. 67
M (SOIC) Package	
Maximum Junction Temperature	150 <sup>o</sup> C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

#### **Operating Conditions**

Temperature Range, T <sub>A</sub> 55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

			ST ITIONS			25°C		-40°C 1	O 85°C	-55°C T	O 125°C				
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS			
HC TYPES															
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V			
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V			
				6	4.2	-	-	4.2	-	4.2	-	V			
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V			
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V			
				6	-	-	1.8	-	1.8	-	1.8	V			
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V			
Voltage CMOS Loads					V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CIVICO LOAGS			-0.02	6	5.9	-	-	5.9	-	5.9	-	V			
High Level Output			-6	4.5	3.98	-	-	3.84	-	3.7	-	٧			
Voltage TTL Loads				-7.8	6	5.48	-	-	5.34	-	5.2	-	V		
Low Level Output	V <sub>OL</sub>	V <sub>OL</sub> V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V			
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V			
OWOO Loads			0.02	6	-	-	0.1	-	0.1	-	0.1	V			
Low Level Output	1		6	4.5	-	-	0.26	-	0.33	-	0.4	V			
Voltage TTL Loads	ds		7.8	6	-	-	0.26	-	0.33	-	0.4	V			
Input Leakage Current	Iį	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μА			
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μА			
Three-State Leakage Current	l <sub>OZ</sub>	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	6	-	-	±0.5	-	±5.0	-	±10	μА			

## DC Electrical Specifications (Continued)

		l	ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	Ī	ı	2	i	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>ОН</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V <sub>CC</sub> to GND	0	5.5	ı	ı	±0.1	1	±1	-	±1	μА
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 3)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА
Three-State Leakage Current	l <sub>OZ</sub>	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5	-	-	±0.5	-	±5.0	-	±10	μА

#### NOTE:

## **HCT Input Loading Table**

INPUT	UNIT LOADS
ŌE1	0.6
All Others	0.55

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g., 360 $\mu$ A max at 25 $^{o}$ C.

## **Switching Specifications** Input $t_r$ , $t_f = 6ns$

		TEST	TEST		°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	105	130	160	ns
Data to Outputs HC/HCT367			4.5	-	21	26	32	ns
			6	-	18	24	27	ns
		C <sub>L</sub> = 15pF	5	8	-	-	-	ns

<sup>3.</sup> For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

# Switching Specifications Input $t_{\text{r}}$ , $t_{\text{f}}$ = 6ns (Continued)

		TEST		25	o°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	MAX	MAX	MAX	UNITS
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	105	130	160	ns
Data to Outputs HC/HCT368			4.5	-	21	26	32	ns
			6	-	18	24	27	ns
		C <sub>L</sub> = 15pF	5	9	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	150	190	225	ns
Output Enable and Disable to Outputs			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C <sub>L</sub> = 15pF	5	12	-	-	-	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	40	-	-	-	pF
HCT TYPES								
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	25	31	38	ns
Data to Outputs HC/HCT367		C <sub>L</sub> = 15pF	5	9	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	30	38	45	ns
Data to Outputs HC/HCT368		C <sub>L</sub> = 15pF	5	11	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	35	44	53	ns
Output Enable and Disable to Outputs		C <sub>L</sub> = 15pF	5	14	-	-	-	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	10	10	10	pF
Three-State Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	42	-	-	-	pF

<sup>4.</sup>  $C_{\mbox{\scriptsize PD}}$  is used to determine the dynamic power consumption, per buffer.

<sup>5.</sup>  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

## Test Circuits and Waveforms

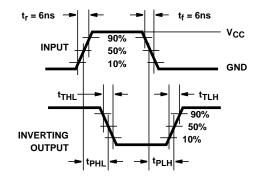


FIGURE 2. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

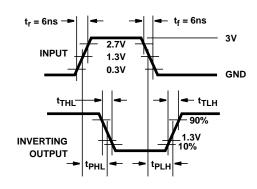


FIGURE 3. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

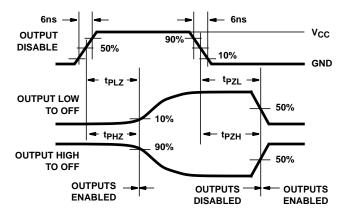


FIGURE 4. HC THREE-STATE PROPAGATION DELAY WAVEFORM

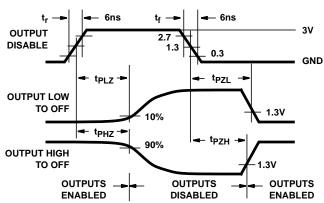
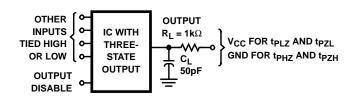


FIGURE 5. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ ,  $C_L = 50pF$ .

FIGURE 6. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT



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## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9070601MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
9070601MEAS2035	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD54HC367F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD54HC368F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD54HCT367F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD74HC367E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC367EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC367M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC368EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC368M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC368MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



**PACKAGE OPTION ADDENDUM** 

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Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD74HCT367E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT367EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT367M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT367MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT368EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT368M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT368MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



#### PACKAGE OPTION ADDENDUM

www.ti.com 15-Oct-2009

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC367M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC368M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT367M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT368M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC367M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC368M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT367M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT368M96	SOIC	D	16	2500	333.2	345.9	28.6

## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

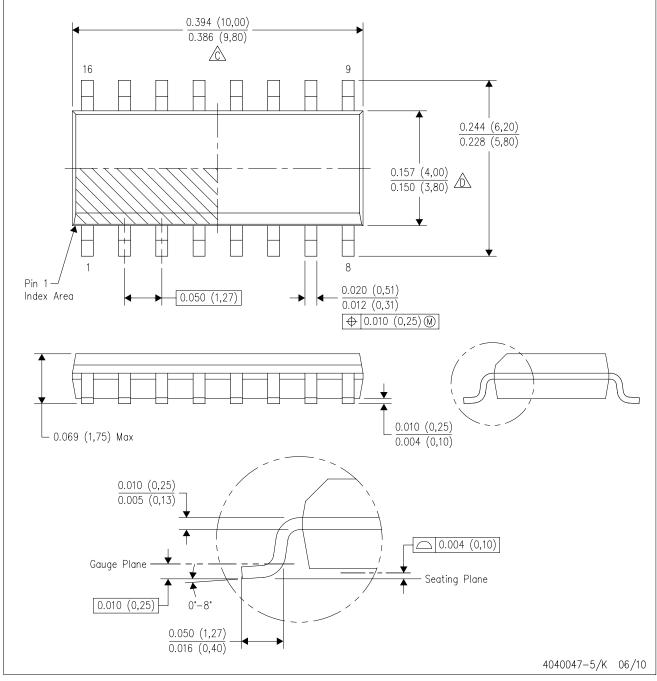


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDS0-G16)

## PLASTIC SMALL-OUTLINE PACKAGE

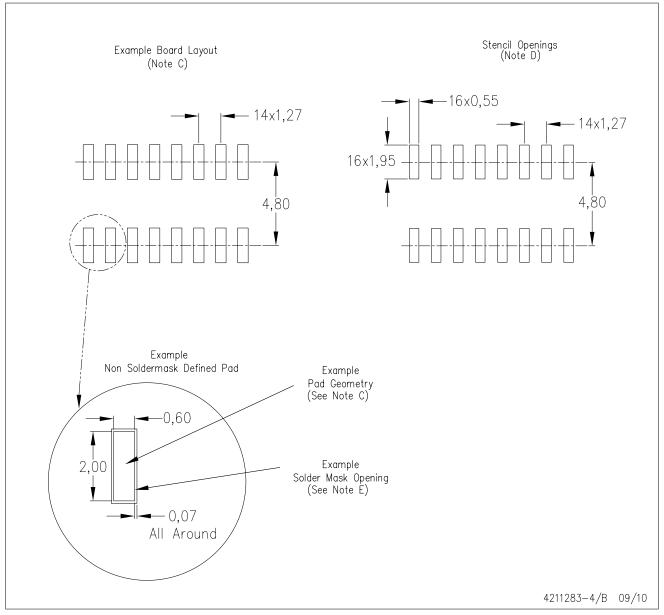


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



# D (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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